

DS90UR907Q 5 - 65 MHz 24-bit Color FPD-Link to FPD-Link II Converter

Check for Samples: DS90UR907Q

FEATURES

- 5 65 MHz Support (140 Mbps to 1.82 Gbps Serial Link)
- 5-Channel (4 data + 1 clock) FPD-Link Receiver Inputs
- AC Coupled STP Interconnect up to 10 Meters in Length
- Integrated Output Termination
- @ Speed Link BIST Mode
- Optional I2C Compatible Serial Control Bus
- RGB888 + VS, HS, DE support
- Power Down Mode Minimizes Power Dissipation
- Randomizer/Scrambler DC-Balanced Data Stream
- Low EMI FPD-Link Input
- Selectable Output VOD and Adjustable De-Emphasis
- 1.8V or 3.3V Compatible Control Bus Interface
- Automotive Grade Product: AEC-Q100 Grade 2 Qualified
- >8 kV HBM and ISO 10605 ESD Rating
- Backward Compatible Mode for Operation with Older Generation Devices

APPLICATIONS

- Automotive Display for Navigation
- Automotive Display for Entertainment

DESCRIPTION

The DS90UR907Q converts FPD-Link to FPD-Link II. It translates four LVDS data/control streams and one LVDS clock pair (FPD-Link) into a high-speed serialized interface (FPD-Link II) over a single pair. This serial bus scheme greatly eases system design by eliminating skew problems between clock and data, reduces the number of connector pins, reduces the interconnect size, weight, and cost, and overall eases PCB layout. In addition, internal DC balanced encoding is used to support AC-coupled interconnects.

The DS90UR907Q converts, balances and level shifts four LVDS data/control streams, and embeds one LVDS clock pair (FPD-Link) to a serial stream (FPD-Link II). Up to 24 bits of RGB in the FPD-Link are serialized along with the three video control signals.

Serial transmission is optimized by a user selectable de-emphasis and differential output level select features. EMI is minimized by the use of low voltage differential signaling and spread spectrum clocking compatibility.

With fewer wires to the physical interface of the host, FPD-Link input with LVDS technology is ideal for high speed, low power and low EMI data transfer.

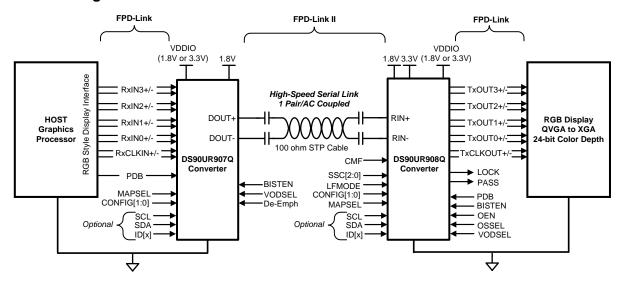
The device is offered in a 36-pin WQFN package and is specified over the automotive AEC-Q100 Grade 2 temperature range of -40°C to +105°C.

M

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Applications Diagram



DS90UR907Q Pin Diagram

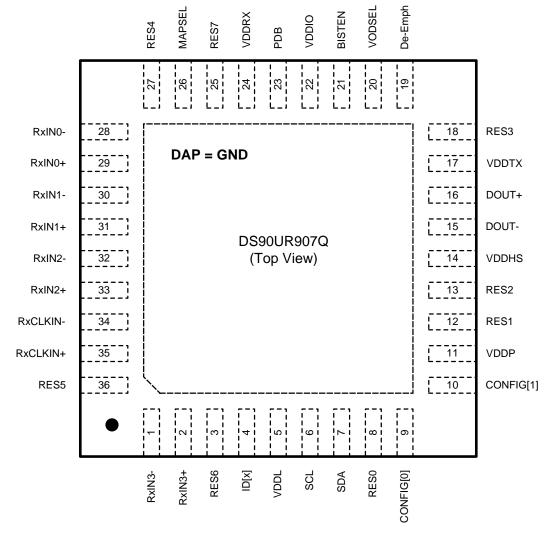


Figure 1. DS90UR907Q — Top View



PIN DESCRIPTIONS

Pin Name	Pin #	I/O, Type	PIN DESCRIPTIONS Description
	nput Interface	#O, Type	Description
RxIN[3:0]+	2, 33, 31, 29	I, LVDS	True LVDS Data Input
TXII ([0.0])	2, 00, 01, 20	1, 2000	This pair requires an external 100 Ω termination for standard LVDS levels.
RxIN[3:0]-	1, 34, 32, 30, 28	I, LVDS	Inverting LVDS Data Input This pair requires an external 100 Ω termination for standard LVDS levels.
RxCLKIN+	35	I, LVDS	True LVDS Clock Input This pair requires an external 100 Ω termination for standard LVDS levels.
RxCLKIN-	34	I, LVDS	Inverting LVDS Clock Input This pair requires an external 100 Ω termination for standard LVDS levels.
Control and	d Configuration		
PDB	23	I, LVCMOS w/ pull-down	Power-down Mode Input PDB = 1, Device is enabled (normal operation). Refer to "POWER UP REQUIREMENTS AND PDB PIN" in the Applications Information Section. PDB = 0, Device is powered down When the Device is in the power-down state, the driver outputs (DOUT+/-) are both logic high, the PLL is shutdown, IDD is minimized. Control Registers are RESET.
VODSEL	20	I, LVCMOS w/ pull-down	Differential Driver Output Voltage Select — Pin or Register Control VODSEL = 1, LVDS VOD is ±450 mV, 900 mVp-p (typ) — Long Cable / De-E Applications VODSEL = 0, LVDS VOD is ±300 mV, 600 mVp-p (typ)
De-Emph	19	I, Analog w/ pull-up	De-Emphasis Control — Pin or Register Control De-Emph = open (float) - disabled To enable De-emphasis, tie a resistor from this pin to GND or control via register. See Table 3
MAPSEL	26	I, LVCMOS w/ pull-down	FPD-Link Map Select — Pin or Register Control MAPSEL = 1, MSB on RxIN3+/ Figure 18 MAPSEL = 0, LSB on RxIN3+/ Figure 17
CONFIG[1:0]	10, 9	I, LVCMOS w/ pull-down	Operating Modes Determine the device operating mode and interfacing device. Table 1 CONFIG[1:0] = 00: Interfacing to DS90UR906 or DS90UR908, Control Signal Filter DISABLED CONFIG[1:0] = 01: Interfacing to DS90UR906 or DS90UR908, Control Signal Filter ENABLED CONFIG [1:0] = 10: Interfacing to DS90UR124, DS99R124 CONFIG [1:0] = 11: Interfacing to DS90C124
ID[x]	4	I, Analog	Serial Control Bus Device ID Address Select — Optional Resistor to Ground and 10 $k\Omega$ pull-up to 1.8V rail. See Table 4.
SCL	6	I, LVCMOS	Serial Control Bus Clock Input - Optional SCL requires an external pull-up resistor to V _{DDIO} .
SDA	7	I/O, LVCMOS Open Drain	Serial Control Bus Data Input / Output - Optional SDA requires an external pull-up resistor V _{DDIO} .
BISTEN	21	I, LVCMOS w/ pull-down	BIST Mode — Optional BISTEN = 1, BIST is enabled BISTEN = 0, BIST is disabled
RES[7:0]	25, 3, 36, 27, 18, 13, 12, 8	I, LVCMOS w/ pull-down	Reserved - tie LOW
FPD-Link II	Serial Interface	l	
DOUT+	16	O, LVDS	True Output. The output must be AC Coupled with a 100 nF capacitor.
DOUT-	15	O, LVDS	Inverting Output. The output must be AC Coupled with a 100 nF capacitor.



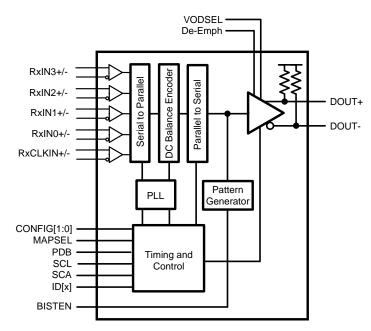
PIN DESCRIPTIONS (continued)

Pin Name	Pin #	I/O, Type	Description			
Power and Ground						
VDDL	5	Power	Logic Power, 1.8 V ±5%			
VDDP	11	Power	PLL Power, 1.8 V ±5%			
VDDHS	14	Power	TX High Speed Logic Power, 1.8 V ±5%			
VDDTX	17	Power	Output Driver Power, 1.8 V ±5%			
VDDRX	24	Power	RX Power, 1.8 V ±5%			
V_{DDIO}	22	Power	LVCMOS I/O Power and FPD-Link I/O Power 1.8 V ±5% OR 3.3 V ±10%			
GND	DAP	Ground	DAP is the large metal contact at the bottom side, located at the center of the WQFN package. Connect to the ground plane (GND) with at least 9 vias.			

Note: 1 = HIGH, 0 = LOW

The VDD (V $_{\text{DDn}}$ and V $_{\text{DDIO}}$) supply ramp should be faster than 1.5 ms with a monotonic rise.

Block Diagram



FDP-Link to FPD-Link II Convertor





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)(2)

Supply Voltage − V _{DDIO} −0.3V to +4.0V LVCMOS I/O Voltage −0.3V to (V _{DDIO} + 0.3V) LVDS Input Voltage −0.3V to (V _{DDIO} + 0.3V) Driver Output Voltage −0.3V to (V _{DDIO} + 0.3V) Junction Temperature +150°C Storage Temperature −65°C to +150°C 36L WQFN Package Maximum Power Dissipation Capacity at 25°C Derate above 25°C 1/ θ _{JA} °C/W θ _{JC} 4.5 °C/W ESD Rating (IEC, powered-up only), R _D = 330Ω, C _S = 150pF Air Discharge (R _{IN+} , R _{IN-}) ≥±30 kV Contact Discharge (R _{IN+} , R _{IN-}) ≥±6 kV ESD Rating (ISO10605), R _D = 330Ω, C _S = 150 & 330pF ≥±15 kV Air Discharge (R _{IN+} , R _{IN-}) ≥±8 kV ESD Rating (ISO10605), R _D = 2kΩ, C _S = 150 & 330pF ≥±15 kV SD Rating (ISO10605), R _D = 2kΩ, C _S = 150 & 330pF ≥±15 kV Contact Discharge (R _{IN+} , R _{IN-}) ≥±8 kV ESD Rating (IBM) ≥±8 kV ESD Rating (HBM) ≥±8 kV ESD Rating (CDM) ≥±1.25 kV	Absolute Maximum Ratings	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Supply Voltage – V _{DDn} (1.8V)	-0.3V to +2.5V
LVDS Input Voltage $-0.3V$ to $(V_{DDIO} + 0.3V)$ Driver Output Voltage $-0.3V$ to $(V_{DDIO} + 0.3V)$ Junction Temperature $+150^{\circ}\text{C}$ Storage Temperat	Supply Voltage – V _{DDIO}	-0.3V to +4.0V
Driver Output Voltage $-0.3V$ to $(V_{DDn} + 0.3V)$ Junction Temperature $+150^{\circ}\mathrm{C}$ Storage Temperature $+150^{\circ}\mathrm{C}$ Storage Temperature $-65^{\circ}\mathrm{C}$ to $+150^{\circ}\mathrm{C}$ 36L WQFN Package $-65^{\circ}\mathrm{C}$ 1/ $\theta_{\mathrm{JA}} \circ \mathrm{C}/\mathrm{C}$ $\theta_{\mathrm{JA}} \circ \mathrm{C}/\mathrm{C}$ $\theta_{\mathrm{JA}} \circ \mathrm{C}/\mathrm{C}$ $\theta_{\mathrm{JA}} \circ \mathrm{C}/\mathrm{C}$ $\theta_{\mathrm{JA}} \circ \mathrm{C}/\mathrm{C}/\mathrm{C}$ $\theta_{\mathrm{JA}} \circ \mathrm{C}/\mathrm{C}/\mathrm{C}/\mathrm{C}/\mathrm{C}/\mathrm{C}/\mathrm{C}/\mathrm{C}/$	LVCMOS I/O Voltage	$-0.3V$ to $(V_{DDIO} + 0.3V)$
Junction Temperature $+150^{\circ}\text{C}$ Storage Temperature -65°C to $+150^{\circ}\text{C}$ 36L WQFN Package -65°C to $+150^{\circ}\text{C}$ Maximum Power Dissipation Capacity at 25°C $1/\theta_{JA} \circ \text{CM}$ Derate above 25°C $1/\theta_{JA} \circ \text{CM}$ θ_{JA} $27.4 \circ \text{CM}$ θ_{JC} $4.5 \circ \text{CM}$ ESD Rating (IEC, powered-up only), $R_D = 330\Omega$, $C_S = 150\text{PF}$ Air Discharge (R_{IN+} , R_{IN-}) $\pm \pm 30 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\pm \pm 6 \text{ kV}$ ESD Rating (ISO10605), $R_D = 330\Omega$, $C_S = 150 \& 330\text{PF}$ Air Discharge (R_{IN+} , R_{IN-}) $\pm \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\pm \pm 8 \text{ kV}$ ESD Rating (ISO10605), $R_D = 2k\Omega$, $C_S = 150 \& 330\text{PF}$ Air Discharge (R_{IN+} , R_{IN-}) $\pm \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\pm \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\pm \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\pm \pm 15 \text{ kV}$ ESD Rating (IBM) $\pm \pm 25 \text{ kV}$ ESD Rating (CDM) $\pm \pm 1.25 \text{ kV}$	LVDS Input Voltage	$-0.3V$ to $(V_{DDIO} + 0.3V)$
Storage Temperature -65°C to $+150^{\circ}\text{C}$ 36L WQFN Package Maximum Power Dissipation Capacity at 25°C $1/\theta_{\text{JA}} \circ \text{C/W}$ θ_{JA} 0 0 0 0 0 0 0 0 0 0	Driver Output Voltage	$-0.3V$ to $(V_{DDn} + 0.3V)$
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Junction Temperature	+150°C
$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	Storage Temperature	−65°C to +150°C
Derate above 25°C 1/ θ _{JA} °C/W $θ_{JA}$ 27.4 °C/W $θ_{JC}$ 4.5 °C/W ESD Rating (IEC, powered-up only), R _D = 330Ω, C _S = 150pF Air Discharge (R _{IN+} , R _{IN-}) ≥±30 kV Contact Discharge (R _{IN+} , R _{IN-}) ≥±6 kV ESD Rating (ISO10605), R _D = 330Ω, C _S = 150 & 330pF Air Discharge (R _{IN+} , R _{IN-}) ≥±15 kV Contact Discharge (R _{IN+} , R _{IN-}) ≥±8 kV ESD Rating (ISO10605), R _D = 2kΩ, C _S = 150 & 330pF Air Discharge (R _{IN+} , R _{IN-}) ≥±15 kV Contact Discharge (R _{IN+} , R _{IN-}) ≥±15 kV Contact Discharge (R _{IN+} , R _{IN-}) ≥±8 kV ESD Rating (HBM) ≥±8 kV ESD Rating (CDM) ≥±1.25 kV	36L WQFN Package	
$\begin{array}{lll} \theta_{JA} & & & 27.4 \text{ °C/W} \\ \theta_{JC} & & & 4.5 \text{ °C/W} \\ \end{array}$ $ESD \ Rating \ (IEC, \ powered-up \ only), \ R_D = 330\Omega, \ C_S = 150pF \\ \\ Air \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 30 \ kV \\ \\ Contact \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 6 \ kV \\ \\ ESD \ Rating \ (ISO10605), \ R_D = 330\Omega, \ C_S = 150 \ \& \ 330pF \\ \\ Air \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 15 \ kV \\ \\ Contact \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 8 \ kV \\ \\ ESD \ Rating \ (ISO10605), \ R_D = 2k\Omega, \ C_S = 150 \ \& \ 330pF \\ \\ Air \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 15 \ kV \\ \\ Contact \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 15 \ kV \\ \\ Contact \ Discharge \ (R_{IN+}, \ R_{IN-}) & & \geq \pm 15 \ kV \\ \\ ESD \ Rating \ (HBM) & & \geq \pm 8 \ kV \\ \\ ESD \ Rating \ (CDM) & & \geq \pm 1.25 \ kV \\ \\ \end{array}$	Maximum Power Dissipation Capacity at 25°C	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Derate above 25°C	1/ θ _{JA} °C/W
ESD Rating (IEC, powered-up only), $R_D = 330\Omega$, $C_S = 150pF$ Air Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) Contact Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) ESD Rating (ISO10605), $R_D = 330\Omega$, $C_S = 150 \& 330pF$ Air Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) Contact Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) ESD Rating (ISO10605), $R_D = 2k\Omega$, $C_S = 150 \& 330pF$ Air Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) ESD Rating (ISO10605), $R_D = 2k\Omega$, $C_S = 150 \& 330pF$ Air Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) Contact Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) ESD Rating (HBM) ESD Rating (HBM) ESD Rating (CDM)	θ_{JA}	27.4 °C/W
Air Discharge (R_{IN+} , R_{IN-}) $\geq \pm 30 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\geq \pm 6 \text{ kV}$ ESD Rating (ISO10605), $R_D = 330\Omega$, $C_S = 150 \& 330pF$ Air Discharge (R_{IN+} , R_{IN-}) $\geq \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\geq \pm 8 \text{ kV}$ ESD Rating (ISO10605), $R_D = 2k\Omega$, $C_S = 150 \& 330pF$ Air Discharge (R_{IN+} , R_{IN-}) $\geq \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\geq \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\geq \pm 15 \text{ kV}$ ESD Rating (HBM) $\geq \pm 15 \text{ kV}$ ESD Rating (CDM)	θ_{JC}	4.5 °C/W
Contact Discharge (R _{IN+} , R _{IN-})≥±6 kVESD Rating (ISO10605), R _D = 330Ω, C _S = 150 & 330pFAir Discharge (R _{IN+} , R _{IN-})≥±15 kVContact Discharge (R _{IN+} , R _{IN-})≥±8 kVESD Rating (ISO10605), R _D = 2kΩ, C _S = 150 & 330pFAir Discharge (R _{IN+} , R _{IN-})≥±15 kVContact Discharge (R _{IN+} , R _{IN-})≥±8 kVESD Rating (HBM)≥±8 kVESD Rating (CDM)≥±1.25 kV	ESD Rating (IEC, powered-up only), $R_D = 330\Omega$, $C_S = 150pF$	
ESD Rating (ISO10605), $R_D = 330Ω$, $C_S = 150 \& 330pF$ Air Discharge (R_{IN+} , R_{IN-}) Contact Discharge (R_{IN+} , R_{IN-}) ESD Rating (ISO10605), $R_D = 2kΩ$, $C_S = 150 \& 330pF$ Air Discharge (R_{IN+} , R_{IN-}) Contact Discharge (R_{IN+} , R_{IN-}) ESD Rating (HBM) ESD Rating (CDM)	Air Discharge (R _{IN+} , R _{IN-})	≥±30 kV
Air Discharge (R_{IN+} , R_{IN-}) $\geq \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\geq \pm 8 \text{ kV}$ ESD Rating (ISO10605), $R_D = 2k\Omega$, $C_S = 150 \& 330pF$ Air Discharge (R_{IN+} , R_{IN-}) $\geq \pm 15 \text{ kV}$ Contact Discharge (R_{IN+} , R_{IN-}) $\geq \pm 8 \text{ kV}$ ESD Rating (HBM) $\geq \pm 8 \text{ kV}$ ESD Rating (CDM)	Contact Discharge (R _{IN+} , R _{IN} -)	≥±6 kV
	ESD Rating (ISO10605), $R_D = 330\Omega$, $C_S = 150 \& 330pF$	
ESD Rating (ISO10605), $R_D = 2kΩ$, $C_S = 150 \& 330pF$ Air Discharge (R_{IN+} , R_{IN-}) Contact Discharge (R_{IN+} , R_{IN-}) ESD Rating (HBM) ESD Rating (CDM) ≥±8 kV ≥±1.25 kV	Air Discharge (R _{IN+} , R _{IN-})	≥±15 kV
Air Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) Contact Discharge ($R_{\text{IN+}}$, $R_{\text{IN-}}$) ESD Rating (HBM) ESD Rating (CDM) $\geq \pm 8 \text{ kV}$ $\geq \pm 1.25 \text{ kV}$	Contact Discharge (R _{IN+} , R _{IN} -)	≥±8 kV
Contact Discharge (R_{IN+} , R_{IN-})≥±8 kVESD Rating (HBM)≥±8 kVESD Rating (CDM)≥±1.25 kV	ESD Rating (ISO10605), $R_D = 2k\Omega$, $C_S = 150 \& 330pF$	
ESD Rating (HBM) ≥±8 kV ESD Rating (CDM) ≥±1.25 kV	Air Discharge (R _{IN+} , R _{IN-})	≥±15 kV
ESD Rating (CDM) ≥±1.25 kV	Contact Discharge (R _{IN+} , R _{IN} -)	≥±8 kV
	ESD Rating (HBM)	≥±8 kV
ESD Rating (MM) ≥±250 V	ESD Rating (CDM)	≥±1.25 kV
	ESD Rating (MM)	≥±250 V

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

Recommended Operating Conditions

	Min	Nom	Max	Units
Supply Voltage (V _{DDn})	1.71	1.8	1.89	V
LVCMOS Supply Voltage (V _{DDIO})	1.71	1.8	1.89	V
OR				
LVCMOS Supply Voltage (V _{DDIO})	3.0	3.3	3.6	V
Operating Free Air Temperature (T _A)	-40	+25	+105	°C
RxCLKIN Frequency	5		65	MHz
Supply Noise ⁽¹⁾			100	mV _{P-P}

(1) Supply noise testing was done with minimum capacitors on the PCB. A sinusoidal signal is AC coupled to the V_{DDn} (1.8V) supply with amplitude = 100 mVp-p measured at the device V_{DDn} pins. Bit error rate testing of input to the Ser and output of the Des with 10 meter cable shows no error when the noise frequency on the Ser is less than 750 kHz. The Des on the other hand shows no error when the noise frequency is less than 400 kHz.



DC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Condit	ions	Pin/Freq.	Min	Тур	Max	Units
LVCMOS	INPUT DC SPECIFICATIONS							
	LPah Lavalla and Maltana	$V_{DDIO} = 3.0 \text{ to } 3.6 \text{V}$			2.2		V_{DDIO}	V
V _{IH}	High Level Input Voltage	$V_{DDIO} = 1.71 \text{ to } 1.89V$,		0.65* V _{DDIO}		V_{DDIO}	V
		$V_{DDIO} = 3.0 \text{ to } 3.6 \text{V}$		PDB,	GND		0.8	V
V_{IL}	Low Level Input Voltage	V _{DDIO} = 1.71 to 1.89V	,	VODSEL, MAPSEL,	GND		0.35* V _{DDIO}	V
L	Input Current	$V_{IN} = 0V \text{ or } V_{DDIO}$	V _{DDIO} = 3.0 to 3.6V	CONFIG[1:0], BISTEN	-15	±1	+15	μΑ
I _{IN}	input current	AIN — OA OL ADDIO	V _{DDIO} = 1.7 to 1.89V		-15	±1	+15	μΑ
FPD-LINK	LVDS RECEIVER DC SPEC	IFICATIONS						
V_{TH}	Differential Threshold High Voltage						+100	- mV
V_{TL}	Differential Threshold Low Voltage	V _{CM} = 1.2V, Figure 2			-100			IIIV
V _{ID}	Differential Input Voltage Swing			RxIN[3:0]+/-, RxCLKIN+/-,	200		600	mV
\ /	Common Mada Valtana	$V_{DDIO} = 3.3V$		-	0	1.2	2.4	V
V_{CM}	Common Mode Voltage	$V_{DDIO} = 1.8V$			0	1.2	1.55	v
I _{IN}	Input Current				- 15	±1	+15	μΑ
FPD-LINK	II LVDS DRIVER DC SPECIF	ICATIONS						
V	Differential Output Voltage		VODSEL = 0		±225	±300	±375	\/
V_{OD}	Differential Output Voltage	$R_L = 100\Omega$, De-emph = disabled,	VODSEL = 1		±350	±450	±550	mV
V	Differential Output Voltage	Figure 4	VODSEL = 0			600		mVp-p
V _{ODp-p}	(DOUT+) – (DOUT-)		VODSEL = 1			900		mVp-p
ΔV_{OD}	Output Voltage Unbalance	$R_L = 100\Omega$, De-emph VODSEL = L	= disabled,			1	50	mV
	Offset Voltage - Single-	$R_L = 100\Omega$,	VODSEL = 0	DOUT+,		1.65		V
Vos	ended At TP A & B, Figure 3	De-emph = disabled	VODSEL = 1	DOUT-		1.575		V
ΔV _{OS}	Offset Voltage Unbalance Single-ended At TP A & B, Figure 3	$R_L = 100\Omega$, De-emph = disabled				1		mV
los	Output Short Circuit Current	DOUT+/- = 0V, De-emph = disabled	VODSEL = 0			-35		mA
R _T	Internal Termination Resistor				80		120	Ω

⁽¹⁾ The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.

⁽²⁾ Typical values represent most likely parametric norms at V_{DD} = 3.3V, Ta = +25 degC, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

⁽³⁾ Current into device pins is defined as positive. Current out of a device pin is defined as negative. Voltages are referenced to ground except VOD, ΔVOD, VTH and VTL which are differential voltages.



DC Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

Symbol	Parameter	Conditi	ons	Pin/Freq.	Min	Тур	Max	Units					
SUPPLY (CURRENT												
I _{DDT1}		Checker Board	V _{DD} = 1.89V	All V _{DD} pins		80	90	mA					
			V _{DDIO} = 1.89V			3	5	mA					
I _{DDIOT1}	Supply Current		V _{DDIO}		10	13	mA						
I _{DDT2}	(includes load current) R _I = 100Ω, f = 65MHz	Checker Board	V _{DD} = 1.89V	All V _{DD} pins		75	85	mA					
		Pattern, De-emph = $6 \text{ k}\Omega$, VODSEL = L, Figure 11	De-emph = $6 \text{ k}\Omega$, VODSEL = L,	,	,	,	,	V _{DDIO} = 1.89V			3	5	mA
I _{DDIOT2}				V _{DDIO} = 3.6V	V _{DDIO}		10	13	mA				
I _{DDZ}		PDB = 0V , (All other	V _{DD} = 1.89V	All V _{DD} pins		60	1000	μΑ					
	Supply Current Power-down	LVCMOS Inputs =	V _{DDIO} = 1.89V			0.5	10	μΑ					
IDDIOZ		0V)	$V_{DDIO} = 3.6V$	V _{DDIO}		1	30	μA					

Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
FPD-LIN	K LVDS INPUT		- !	*	-	
t _{RSP0}	Receiver Strobe Position-bit 0		0.66	1.10	1.54	ns
t _{RSP1}	Receiver Strobe Position-bit 1		2.86	3.30	3.74	ns
t _{RSP2}	Receiver Strobe Position-bit 2	RXCLKIN = 65 MHz.	5.05	5.50	5.93	ns
t _{RSP3}	Receiver Strobe Position-bit 3	RxIN[3:0]	7.25	7.70	8.13	ns
t _{RSP4}	Receiver Strobe Position-bit 4	Figure 6	9.45	9.90	10.33	ns
t _{RSP5}	Receiver Strobe Position-bit 5		11.65	12.10	12.53	ns
t _{RSP6}	Receiver Strobe Position-bit 6		13.85	14.30	14.73	ns
FPD-LIN	IK II LVDS OUTPUT					
t _{HLT}	Output Low-to-High Transition	$R_L = 100\Omega$, De-emphasis = disabled, VODSEL = 0		200		ps
	Time, Figure 5	R_L = 100Ω, De-emphasis = disabled, VODSEL = 1		200		ps
t _{HLT}	Output High-to-Low Transition	$R_L = 100\Omega$, De-emphasis = disabled, VODSEL = 0		200		ps
	Time, Figure 5	R_L = 100Ω, De-emphasis = disabled, VODSEL = 1		200		ps
t _{XZD}	Ouput Active to OFF Delay, Figure 8			5	15	ns
t _{PLD}	PLL Lock Time, Figure 7	$R_L = 100\Omega^{(1)}$		1.5	10	ms
t _{SD}	Delay - Latency, Figure 9	$R_L = 100\Omega$		140*T	145*T	ns
t _{DJIT}	Output Total Jitter, Figure 10	R_L = 100 Ω , De-Emph = disabled, RANDOM pattern, RxCLKIN = 43 & 65 MHz ⁽²⁾		0.26		UI
λ _{STXBW}	Jitter Transfer	RxCLKIN = 43 MHz		2.2		N.41.1-
	Function -3 dB Bandwidth (3) (4)	RxCLKIN = 65 MHz		3		MHz
δ_{STX}	Jitter Transfer	RxCLKIN = 43 MHz		1		٩D
	Function Peaking ⁽³⁾⁽⁴⁾	RxCLKIN = 65 MHz		1		dB

⁽¹⁾ t_{PLD} is the time required by the device to obtain lock when exiting power-down state with an active RxCLKIN.

⁽²⁾ UI – Unit Interval is equivalent to one serialized data bit width (1UI = 1 / 28*RxCLKIN). The UI scales with RxCLKIN frequency.

⁽³⁾ Specification is ensured by characterization and is not tested in production.

⁴⁾ Specification is ensured by design and is not tested in production.



Recommended Timing for the Serial Control Bus

Over 3.3V supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
f _{SCL}	CCI. Clash Francisco	Standard Mode	0		100	kHz
	SCL Clock Frequency	Fast Mode	0		400	kHz
t_{LOW}	OOL Law Baria I	Standard Mode	4.7			us
	SCL Low Period	Fast Mode	1.3			us
t _{HIGH}	CCL Lligh Daried	Standard Mode	4.0			us
	SCL High Period	Fast Mode	0.6			us
t _{HD;STA}	Hold time for a start or a	Standard Mode	4.0			us
	repeated start condition, Figure 13	Fast Mode	0.6			us
t _{SU:STA}	Set Up time for a start or a	Standard Mode	4.7			us
	repeated start condition, Figure 13	Fast Mode	0.6			us
t _{HD;DAT}	Data Hold Time,	Standard Mode	0		3.45	us
	Figure 13	Fast Mode	0		0.9	us
t _{SU;DAT}	Data Set Up Time,	Standard Mode	250			ns
	Figure 13	Fast Mode	100			ns
t _{SU;STO}	Set Up Time for STOP	Standard Mode	4.0			us
	Condition, Figure 13	Fast Mode	0.6			us
t _{BUF}	Bus Free Time	Standard Mode	4.7			us
	Between STOP and START, Figure 13	Fast Mode	1.3			us
t _r	SCL & SDA Rise Time,	Standard Mode			1000	ns
	Figure 13	Fast Mode			300	ns
t _f	SCL & SDA Fall Time,	Standard Mode			300	ns
	Figure 13	Fast mode			300	ns

DC and AC Serial Control Bus Characteristics

Over 3.3V supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{IH}	Input High Level	SDA and SCL	0.7* V _{DDIO}		V _{DDIO}	V
V_{IL}	Input Low Level Voltage	SDA and SCL	GND		0.3* V _{DDIO}	V
V_{HY}	Input Hysteresis			>50		mV
V _{OL}		SDA, IOL = 1.25mA	0		0.36	V
I _{in}		SDA or SCL, Vin = V _{DDIO} or GND	-10		+10	μΑ
t _R	SDA RiseTime – READ	CDA DDU 401-0 Ch < 400-5 Figure 40		430		ns
t _F	SDA Fall Time - READ	SDA, RPU = $10k\Omega$, Cb $\leq 400pF$, Figure 13		20		ns
t _{SU;DAT}	Set Up Time — READ	See Figure 13		560		ns
t _{HD;DAT}	Hold Up Time — READ	See Figure 13		615		ns
t _{SP}	Input Filter			50		ns
C _{in}	Input Capacitance	SDA or SCL		<5		pF



AC Timing Diagrams and Test Circuits

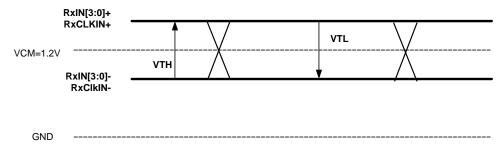


Figure 2. FPD-Link DC VTH/VTL Definition

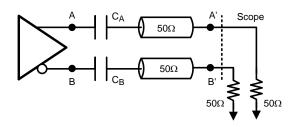


Figure 3. Output Test Circuit

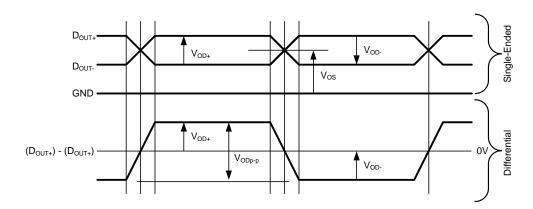


Figure 4. Output Waveforms

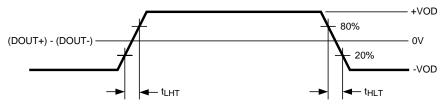


Figure 5. Output Transition Times

Copyright © 2009–2013, Texas Instruments Incorporated



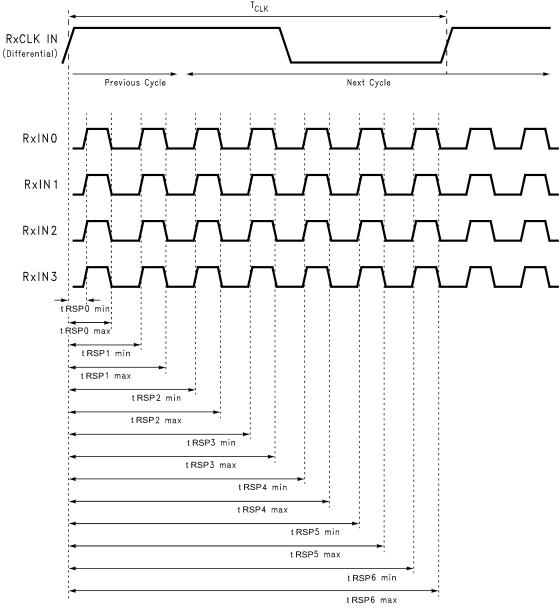


Figure 6. FPD-Link Input Jitter Tolerance

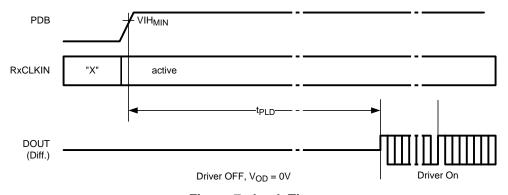


Figure 7. Lock Time



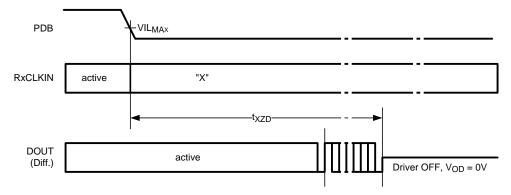


Figure 8. Disable Time

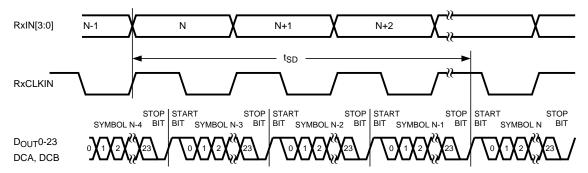


Figure 9. Latency Delay

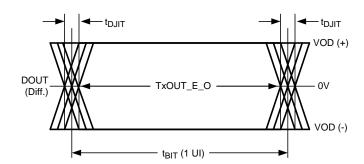


Figure 10. Output Jitter

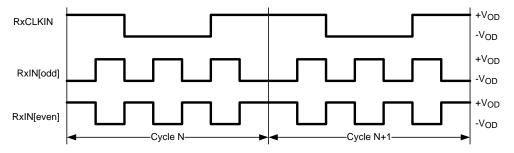


Figure 11. Checkerboard Data Pattern



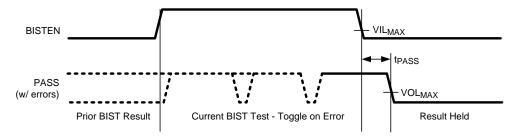


Figure 12. BIST PASS Waveform

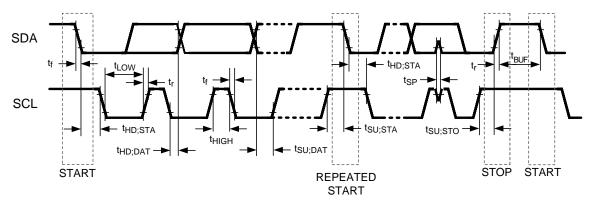


Figure 13. Serial Control Bus Timing Diagram

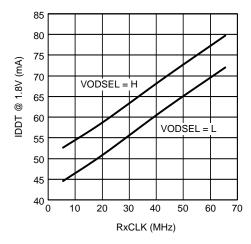


Figure 14. Typical IDDT (1.8V Supply) Current as a function of RxCLK



Functional Description

The DS90UR907Q converter transmits an FPD-Link interface (4 LVDS data channels + 1 LVDS clock) with total of 27-bits of data (24-high speed bits and 3 low speed video control signals) over a single serial FPD-Link II pair. The serial stream also contains an embedded clock and the DC-balance information which enhances signal quality and supports AC coupling. The device is intended for use with DS90UR908Q or DS90UR906Q, but is backward compatible with previous generations of FPD-Link II as well.

The DS90UR907Q can operate in 24-bit color mode(with VS,HS,DE encoded in the serial stream) or in 18-bit color mode.

The DS90UR907Q can be configured via external pins or through the optional serial control bus. It features enhance signal quality on the link by supporting: selectable VOD level, selectable de-emphasis signal conditioning and also the FPD-Link II data coding that provides randomization, scrambling, and DC Balanacing of the video data. It also includes multiple features to reduce EMI associated with display data transmission. This includes the randomization and scrambling of the data and also the system spread spectrum PCLK support. The DS90UR907Q features power saving with a powerdown mode, and auto stop clock feature.

See also the Functional Description of the serial control bus and BIST modes.

The Block Diagram is shown at the beginning of this datasheet.

DATA TRANSFER

The DS90UR907Q transmits a pixel of data in the following format: C1 and C0 represent the embedded clock in the serial stream. C1 is always HIGH and C0 is always LOW. b[23:0] contain the scrambled RGB data. DCB is the DC-Balanced control bit. DCB is used to minimize the short and long-term DC bias on the signal lines. This bit determines if the data is unmodified or inverted. DCA is used to validate data integrity in the embedded data stream and can also contain encoded control (VS,HS,DE). Both DCA and DCB coding schemes are generated by the DS90UR907Q and decoded by the paring deserializer automatically. Figure 15 illustrates the serial stream per PCLK cycle.

Note: The figure only illustrates the bits but does not actually represent the bit location as the bits are scrambled and balanced continuously.

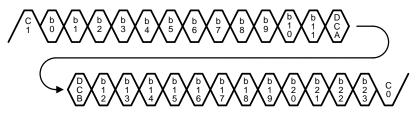


Figure 15. FPD-Link II Serial Stream

OPERATING MODES AND BACKWARD COMPATIBILITY (CONFIG[1:0])

The DS90UR907Q is backward compatible with previous generations of FPD-Link II deserializers. Configuration modes are provided for backwards compatibility with the DS90C124 FPD-Link II Generation 1, and also the DS90UR124 FPD-Link II Generation 2 deserializers by setting the respective mode with the CONFIG[1:0] pins as shown in Table 1. The selection also determine whether the Video Control Signal filter feature is enabled or disabled in Normal mode.

Table 1. DS90UR907Q Configuration Modes

CON FIG1	CON FIG0	Mode	Des Device
L	L	Normal Mode, Control Signal Filter disabled	DS90UR908Q, DS90UR906Q
L	Н	Normal Mode, Control Signal Filter enabled	DS90UR908Q, DS90UR906Q
Н	L	Backwards Compatible GEN2	DS90UR124, DS99R124
Н	Н	Backwards Compatible GEN1	DS90C124

Copyright © 2009–2013, Texas Instruments Incorporated



VIDEO CONTROL SIGNAL FILTER

When operating the devices in Normal Mode, the Video Control Signals (DE, HS, VS) have the following restrictions:

- Normal Mode with Control Signal Filter Enabled:
 - DE and HS Only 2 transitions per 130 clock cycles are transmitted, the transition pulse must be 3 PCLK or longer.
- Normal Mode with Control Signal Filter Disabled:
 - DE and HS Only 2 transitions per 130 clock cycles are transmitted, no restriction on minimum transition pulse.
- VS Only 1 transition per 130 clock cycles are transmitted, minimum pulse width is 130 clock cycles.

Video Control Signals are defined as low frequency signals with limited transitions. Glitches of a control signal can cause a visual display error. This feature allows for the chipset to validate and filter out any high frequency noise on the control signals. See Figure 16.

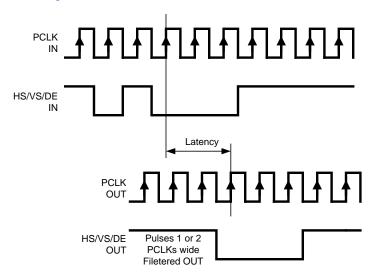


Figure 16. Video Control Signal Filter Wavefrom

COLOR BIT MAPPING SELECT

The DS90UR907Q can be configured to accept 24-bit color (8-bit RGB) with 2 different mapping schemes: LSBs on RxIN[3] shown in Figure 17 or MSBs on RxIN[3] shown in Figure 18. The mapping scheme is controlled by MAPSEL pin or by Register.

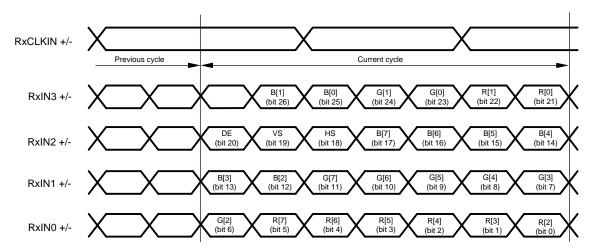


Figure 17. 8-bit FPD-LInk Mapping: LSB's on RxIN3



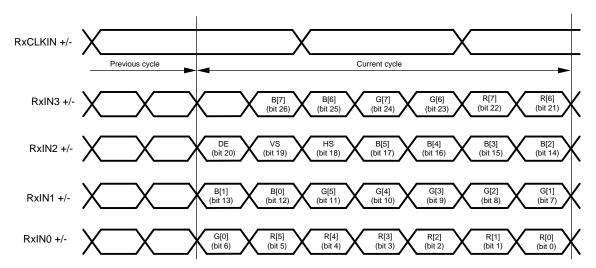


Figure 18. 8-bit FPD-LInk Mapping: MSB's on RxIN3

EMI REDUCTION FEATURES

Spread Spectrum Compatibility

The RxCLKIN of the FPD-Link input is capable of tracking spread spectrum clocking (SSC) from a host source. The RxCLKIN will accept spread spectrum, tracking up to 35kHz modulation and ± 0.5 , ± 1 or $\pm 2\%$ deviations (center spread). The maximum conditions for the RxCLKIN input are: a modulation frequency of 35kHz and amplitude deviations of $\pm 2\%$ (4% total).

SIGNAL QUALITY ENHANCERS

VOD Select (VODSEL)

The DS90UR907Q differential output voltage may be increased by setting the VODSEL pin High. When VODSEL is Low, the DC VOD is at the standard (default) level. When VODSEL is High, the DC VOD is increased in level. The increased VOD is useful in extremely high noise environments and also on extra long cable length applications. When using de-emphasis it is recommended to set VODSEL = H to avoid excessive signal attenuation especially with the larger de-emphasis settings. This feature may be controlled by the external pin or by register.

Table 2. Differential Output Voltage

Input	Eff	ect
VODSEL	VOD (mV)	VOD (mVp-p)
Н	±450	900
L	±300	600

De-Emphasis (De-Emph)

The De-Emph pin controls the amount of de-emphasis beginning one full bit time after a logic transition that the device drives. It is the signal conditioning function for use in compensating against cable transmission loss. This pin should be left open for standard switching currents (no de-emphasis) or if controlled by register. De-emphasis is selected by connecting a resistor on this pin to ground, with R value between 0.5 k Ω to 1 M Ω , or by register setting. When using De-Emphasis it is recommended to set VODSEL = H.



Table 3. De-Emphasis Resistor Value

Resistor Value (kΩ)	De-Emphasis Setting
Open	Disabled
0.6	- 12 dB
1.0	- 9 dB
2.0	- 6 dB
5.0	- 3 dB

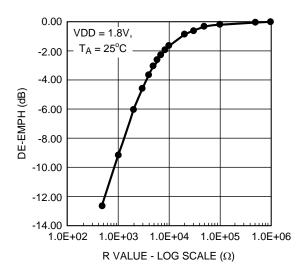


Figure 19. De-Emph vs. R value

POWER SAVING FEATURES

Power Down Feature (PDB)

The DS90UR907Q has a PDB input pin to ENABLE or POWER DOWN the device. This pin is controlled by the host and is used to save power, disabling the link when the display is not needed. In the POWER DOWN mode, the high-speed driver outputs are both pulled to VDD and present a 0V VOD state. Note – in POWER DOWN, the optional Serial Bus Control Registers are **RESET**.

Stop Clock Feature

The DS90UR907Q will enter a low power SLEEP state when the RxCLKIN is stopped. A STOP condition is detected when the input clock frequency is less than 3 MHz. The clock should be held at a static Low or high state. When the RxCLKIN starts again, the device will then lock to the valid input RxCLKIN and then transmits the RGB data to the deserializer. Note – in STOP CLOCK SLEEP, the optional Serial Bus Control Registers values are **RETAINED**.

1.8V or 3.3V VDDIO Operation

The DS90UR907Q parallel control bus operate with 1.8 V or 3.3 V levels (V_{DDIO}) for host compatibility. The 1.8 V levels will offer a system power savings.

OPTIONAL SERIAL BUS CONTROL

Please see the following section on the Optional Serial Bus Control Interface.



Built In Self Test (BIST)

An optional At-Speed Built In Self Test (BIST) feature supports the testing of the high-speed serial link. This is useful in the prototype stage, equipment production, in-system test and also for system diagnostics. In the BIST mode only a input clock is required along with control to the DS90UR907Q and deserializer BISTEN input pins. The DS90UR907Q outputs a test pattern (PRBS7) and drives the link at speed. The deserializer detects the PRBS7 pattern and monitors it for errors. A PASS output pin toggles to flag any payloads that are received with 1 to 24 errors. Upon completion of the test, the result of the test is held on the PASS output until reset (new BIST test or Power Down). A high on PASS indicates NO ERRORS were detected. A Low on PASS indicates one or more errors were detected. The duration of the test is controlled by the pulse width applied to the deserializer BISTEN pin.

Inter-operability is supported between this FPD-Link II device and all FPD-Link II generations (Gen 1/2/3) — see respective datasheets for details on entering BIST mode and control.

Sample BIST Sequence

See Figure 20 for the BIST mode flow diagram.

Step 1: Place the DS90UR907Q in BIST Mode by setting Ser BISTEN = H. The BIST Mode is enabled via the BISTEN pin. An RxCLKIN is required for all the Ser options. When the deserializer detects the BIST mode pattern and command (DCA and DCB code) the RGB and control signal outputs are shut off.

Step 2: Place the pairing deserializer in BIST mode by setting the BISTEN = H. The Des is now in the BIST mode and checks the incoming serial payloads for errors. If an error in the payload (1 to 24) is detected, the PASS pin will switch low for one half of the clock period. During the BIST test, the PASS output can be monitored and counted to determine the payload error rate.

Step 3: To Stop the BIST mode, the deserializer BISTEN pin is set Low. The deserializer stops checking the data and the final test result is held on the PASS pin. If the test ran error free, the PASS output will be High. If there was one or more errors detected, the PASS output will be Low. The PASS output state is held until a new BIST is run, the device is RESET, or Powered Down. The BIST duration is user controlled by the duration of the BISTEN signal.

Step 4: To return the link to normal operation, the DS90UR907Q BISTEN input is set Low. The Link returns to normal operation.

Figure 21 shows the waveform diagram of a typical BIST test for two cases. Case 1 is error free, and Case 2 shows one with multiple errors. In most cases it is difficult to generate errors due to the robustness of the link (differential data transmission etc.), thus they may be introduced by greatly extending the cable length, faulting the interconnect, reducing signal condition enhancements (De-Emphasis, VODSEL, or deserializer Equalization).

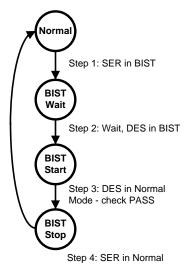


Figure 20. BIST Mode Flow Diagram



BER Calculations

It is possible to calculate the approximate Bit Error Rate (BER). The following is required:

- Pixel Clock Frequency (MHz)
- BIST Duration (seconds)
- BIST test Result (PASS)

The BER is less than or equal to one over the product of 24 times the RxCLKIN rate times the test duration. If we assume a 65MHz RxCLKIN, a 10 minute (600 second) test, and a PASS, the BERT is \leq 1.07 X 10E-12

The BIST mode runs a check on the data payload bits. The LOCK pin also provides a link status. It the recovery of the C0 and C1 bits does not reconstruct the expected clock signal, the LOCK pin will switch Low. The combination of the LOCK and At-Speed BIST PASS pin provides a powerful tool for system evaluation and performance monitoring.

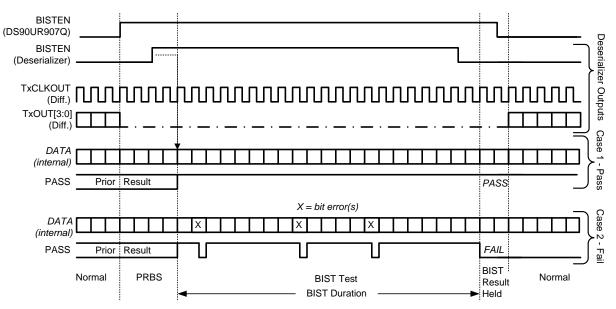


Figure 21. BIST Waveforms

Optional Serial Bus Control

The DS90UR907Q may be configured by the use of a serial control bus that is I2C protocol compatible. By default, the I2C reg_0x00'h is set to 00'h and all configuration is set by control/strap pins. A write of 01'h to reg_0x00'h will enable/allow configuration by registers; this will override the control/strap pins. Multiple devices may share the serial control bus since multiple addresses are supported. See Figure 22.

The serial bus is comprised of three pins. The SCL is a Serial Bus Clock Input. The SDA is the Serial Bus Data Input / Output signal. Both SCL and SDA signals require an external pull up resistor to V_{DDIO} . For most applications a 4.7 k pull up resistor to V_{DDIO} may be used. The resistor value may be adjusted for capacitive loading and data rate requirements. The signals are either pulled High, or driven Low.



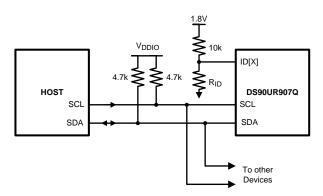


Figure 22. Serial Control Bus Connection

The third pin is the ID[X] pin. This pin sets one of four possible device addresses. Two different connections are possible. The pin may be pulled to V_{DD} (1.8V, NOT V_{DDIO})) with a 10 k Ω resistor. Or a 10 k Ω pull up resistor (to V_{DD} 1.8V, NOT V_{DDIO})) and a pull down resistor of the recommended value to set other three possible addresses may be used. See Table 4.

The Serial Bus protocol is controlled by START, START-Repeated, and STOP phases. A START occurs when SCL transitions Low while SDA is High. A STOP occurs when SDA transition High while SCL is also HIGH. See Figure 23.

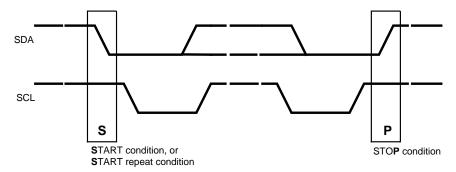


Figure 23. START and STOP Conditions

To communicate with a remote device, the host controller (master) sends the slave address and listens for a response from the slave. This response is referred to as an acknowledge bit (ACK). If a slave on the bus is addressed correctly, it Acknowledges (ACKs) the master by driving the SDA bus low. If the address doesn't match a device's slave address, it Not-acknowledges (NACKs) the master by letting SDA be pulled High. ACKs also occur on the bus when data is being transmitted. When the master is writing data, the slave ACKs after every data byte is successfully received. When the master is reading data, the master ACKs after every data byte is received to let the slave know it wants to receive another data byte. When the master wants to stop reading, it NACKs after the last data byte and creates a stop condition on the bus. All communication on the bus begins with either a Start condition or a Repeated Start condition. All communication on the bus ends with a Stop condition. A READ is shown in Figure 24 and a WRITE is shown in Figure 25.

If the Serial Bus is not required, the three pins may be left open (NC).

Table 4. ID[x] Resistor Value – DS90UR907Q

Resistor RID kΩ	Address 7'b	Address 8'b 0 appended (WRITE)
0.47	7b' 110 1001 (h'69)	8b' 1101 0010 (h'D2)
2.7	7b' 110 1010 (h'6A)	8b' 1101 0100 (h'D4)
8.2	7b' 110 1011 (h'6B)	8b' 1101 0110 (h'D6)
Open	7b' 110 1110 (h'6E)	8b' 1101 1100 (h'DC)



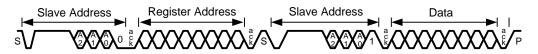


Figure 24. Serial Control Bus — READ

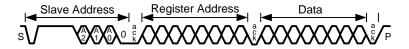


Figure 25. Serial Control Bus — WRITE

Table 5. Serial Bus Control Registers

ADD (dec)	ADD (hex)	Register Name	Bit(s)	R/W	Defau It (bin)	Function	Description
0 0 Ser 0		Ser Config 1	7	R/W	0	Reserved	Reserved
			6	R/W	0	MAPSEL	0: LSB on RxIN3 1: MSB on RxIN3
			5	R/W	0	VODSEL	0: Low 1: High
			4	R/W	0	Reserved	Reserved
			3:2	R/W	00	CONFIG	00: Normal Mode, Control Signal Filter DISABLED 01: Normal Mode, Control Signal Filter ENABLED 10: Backwards Compatible (DS90UR124, DS99R124) 11: Backwards Compatible (DS90C124)
			1	R/W	0	SLEEP	Note – not the same function as PowerDown (PDB) 0: normal mode 1: Sleep Mode – Register settings retained.
			0	R/W	0	REG	Configurations set from control pins Configuration set from registers (except I2C_ID)
1	1	Device ID	7	R/W	0	REG ID	O: Address from ID[X] Pin 1: Address from Register
			6:0	R/W	11010 00	ID[X]	Serial Bus Device ID, Five IDs are: 7b '1101 000 (h'68) 7b '1101 001 (h'69) 7b '1101 010 (h'6A) 7b '1101 011 (h'6B) 7b '1101 110 (h'6E) All other addresses are <i>Reserved</i> .
2	2	De-Emphasis Control	7:5	R/W	000	De-E Setting	000: set by external Resistor 001: -1 dB 010: -2 dB 011: -3.3 dB 100: -5 dB 101: -6.7 dB 110: -9 dB 111: -12 dB
			4	R/W	0	De-E EN	0: De-Emphasis Enabled 1: De-Emphasis Disabled
			3:0	R/W	000	Reserved	Reserved



APPLICATIONS INFORMATION

DISPLAY APPLICATION

The DS90UR907Q and DS90UR908Q chipset is intended for interface between a host (graphics processor) and a Display. It supports an 24-bit color depth (RGB888) and up to 1024 X 768 display formats. In a RGB888 application, 24 color bits (R[7:0], G[7:0], B[7:0]), Pixel Clock (PCLK) and three control bits (VS, HS and DE) are supported across the serial link with PCLK rates from 5 to 65 MHz. The chipset may also be used in 18-bit color applications. In this application three to six general purpose signals may also be sent from host to display.

TYPICAL APPLICATION CONNECTION

Figure 26 shows a typical application of the DS90UR907Q for a 65 MHz 24-bit Color Display Application. The LVDS inputs of the FPD-Link interface require external 100Ω terminations. The LVDS outputs of FPD-Link II require 100 nF AC coupling capacitors to the line. The line driver includes internal termination. Bypass capacitors are placed near the power supply pins. At a minimum, four 0.1 μF capacitors and a 4.7 μF capacitor should be used for local device bypassing. System GPO (General Purpose Output) signals control the PDB and BISTEN pins. The application assumes the companion deserializer (DS90UR908Q) therefore the configuration pins are also both tied Low. In this example the cable is long, therefore the VODSEL pin is tied High and a De-Emphasis value is selected by the resistor R1. The interface to the host is with 1.8 V LVCMOS levels, thus the VDDIO pin is connected also to the 1.8V rail. The Optional Serial Bus Control is not used in this example, thus the SCL, SDA and ID[x] pins are left open. A delay capacitor and resistor is placed on the PDB signal to delay the enabling of the device until power is stable. Bypass capacitors are placed near the power supply pins. Ferrite beads are placed on the power lines for effective noise suppression.

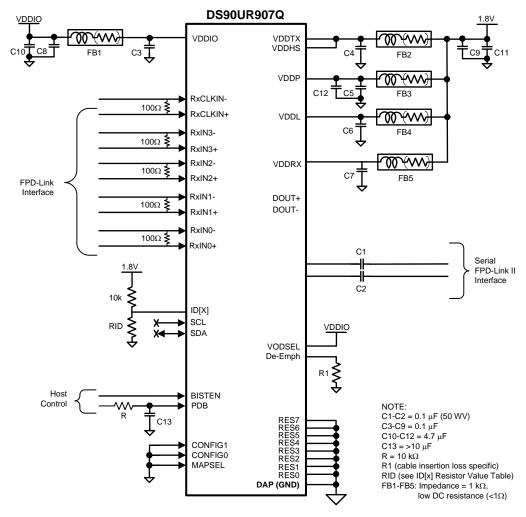


Figure 26. Typical Connection Diagram



POWER UP REQUIREMENTS AND PDB PIN

The VDD (V_{DDn} and V_{DDIO}) supply ramp should be faster than 1.5 ms with a monotonic rise. If slower then 1.5 ms then a capacitor on the PDB pin is needed to ensure PDB arrives after all the VDD have settled to the recommended operating voltage. When PDB pin is pulled to V_{DDIO} , it is recommended to use a 10 k Ω pull-up and a 22 uF cap to GND to delay the PDB input signal.

TRANSMISSION MEDIA

The DS90UR907Q and the companion deserializer chipset is intended to be used in a point-to-point configuration, through a PCB trace, or through twisted pair cable. The DS90UR907Q provide internal terminations providing a clean signaling environment. The interconnect for LVDS should present a differential impedance of 100 Ohms. Use cables and connectors that have matched differential impedance to minimize impedance discontinuities. Shielded or un-shielded cables may be used depending upon the noise environment and application requirements.

ALTERNATE COLOR / DATA MAPPING

Color Mapped data pin names are provided to specify a recommended mapping for 24-bit and 18-bit Applications. When connecting to earlier generations of FPD-Link II deserializer devices, a color mapping review is recommended to ensure the correct connectivity is obtained. Table 6 provides examples for interfacing between DS90UR907Q and different deserializers.

Table 6. Alternate Color / Data Mapping

FPD-Link	Bit Number	RGB (LSB Example)	DS90UR906Q	DS90UR124	DS99R124Q	DS90C124
RxIN3	Bit 26	B1	B1		N/A	
	Bit 25	В0	B0			
	Bit 24	G1	G1			
	Bit 23	G0	G0			
	Bit 22	R1	R1			
	Bit 21	R0	R0			
RxIN2	Bit 20	DE	DE	ROUT20	TxOUT2	ROUT20
	Bit 19	VS	VS	ROUT19		ROUT19
	Bit 18	HS	HS	ROUT18		ROUT18
	Bit 17	В7	B7	ROUT17		ROUT17
	Bit 16	B6	B6ROUT10	ROUT16		ROUT16
	Bit 15	B5	B5	ROUT15		ROUT15
	Bit 14	B4	B4	ROUT14		ROUT14
RxIN1	Bit 13	В3	В3	ROUT13	TxOUT1	ROUT13
	Bit 12	B2	B2	ROUT12		ROUT12
	Bit 11	G7	G7	ROUT11		ROUT11
	Bit 10	G6	G6	ROUT10		ROUT10
	Bit 9	G5	G5	ROUT9		ROUT9
	Bit 8	G4	G4	ROUT8		ROUT8
	Bit 7	G3	G3	ROUT7		ROUT7
RxIN0	Bit 6	G2	G2	ROUT6	TxOUT0	ROUT6
	Bit 5	R7	R7	ROUT5		ROUT5
	Bit 4	R6	R6	ROUT4]	ROUT4
	Bit 3	R5	R5	ROUT3		ROUT3
	Bit 2	R4	R4	ROUT2		ROUT2
	Bit 1	R3	R3	ROUT1]	ROUT1
	Bit 0	R2	R2	ROUT0	1	ROUT0



Table 6. Alternate Color / Data Mapping (continued)

FPD-Link	Bit Number	RGB (LSB Example)		DS90UR906Q	DS90UR124	DS99R124Q	DS90C124
					ROUT23*	OS2*	ROUT23*
* These hits are	N/A e not supported	by DS90UR907Q		N/A	ROUT22*	OS1*	ROUT22*
mood bits and	* These bits are not supported by DS90UR907Q				ROUT21*	OS0*	ROUT21*
DS90UR907Q MAPSEL = 0 Settings			CONFIG [1:0] = 00	CONFIG [1:0] = 10		CONFIG [1:0] = 11	

PCB LAYOUT AND POWER SYSTEM CONSIDERATIONS

Circuit board layout and stack-up for the LVDS devices should be designed to provide low-noise power feed to the device. Good layout practice will also separate high frequency or high-level inputs and outputs to minimize unwanted stray noise pickup, feedback and interference. Power system performance may be greatly improved by using thin dielectrics (2 to 4 mils) for power / ground sandwiches. This arrangement provides plane capacitance for the PCB power system with low-inductance parasitics, which has proven especially effective at high frequencies, and makes the value and placement of external bypass capacitors less critical. External bypass capacitors should include both RF ceramic and tantalum electrolytic types. RF capacitors may use values in the range of 0.01 uF to 0.1 uF. Tantalum capacitors may be in the 2.2 uF to 10 uF range. Voltage rating of the tantalum capacitors should be at least 5X the power supply voltage being used.

Surface mount capacitors are recommended due to their smaller parasitics. When using multiple capacitors per supply pin, locate the smaller value closer to the pin. A large bulk capacitor is recommend at the point of power entry. This is typically in the 50uF to 100uF range and will smooth low frequency switching noise. It is recommended to connect power and ground pins directly to the power and ground planes with bypass capacitors connected to the plane with via on both ends of the capacitor. Connecting power or ground pins to an external bypass capacitor will increase the inductance of the path.

A small body size X7R chip capacitor, such as 0603, is recommended for external bypass. Its small body size reduces the parasitic inductance of the capacitor. The user must pay attention to the resonance frequency of these external bypass capacitors, usually in the range of 20-30 MHz. To provide effective bypassing, multiple capacitors are often used to achieve low impedance between the supply rails over the frequency of interest. At high frequency, it is also a common practice to use two vias from power and ground pins to the planes, reducing the impedance at high frequency.

Some devices provide separate power and ground pins for different portions of the circuit. This is done to isolate switching noise effects between different sections of the circuit. Separate planes on the PCB are typically not required. Pin Description tables typically provide guidance on which circuit blocks are connected to which power pin pairs. In some cases, an external filter many be used to provide clean power to sensitive circuits such as PLLs.

Use at least a four layer board with a power and ground plane. Locate LVCMOS signals away from the LVDS lines to prevent coupling from the LVCMOS lines to the LVDS lines. Closely-coupled differential lines of 100 Ohms are typically recommended for LVDS interconnect. The closely coupled lines help to ensure that coupled noise will appear as common-mode and thus is rejected by the receivers. The tightly coupled lines will also radiate less.



LVDS INTERCONNECT GUIDELINES

See SNLA008 and SNLA035 for full details.

- Use 100Ω coupled differential pairs
- Use the S/2S/3S rule in spacings
 - S = space between the pair
 - 2S = space between pairs
 - 3S = space to LVCMOS signal
- · Minimize the number of Vias
- Use differential connectors when operating above 500Mbps line speed
- Maintain balance of the traces
- · Minimize skew within the pair
- Terminate as close to the TX outputs and RX inputs as possible

Additional general guidance can be found in the LVDS Owner's Manual - available in PDF format from the TI web site at: www.ti.com/lvds





REVISION HISTORY

Changes from Revision E (April 2013) to Revision F						
•	Changed layout of National Data Sheet to TI format	24				



PACKAGE OPTION ADDENDUM

16-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
DS90UR907QSQ/NOPB	ACTIVE	WQFN	NJK	36	1000	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 105	UR907QSQ	Samples
DS90UR907QSQE/NOPB	ACTIVE	WQFN	NJK	36	250	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 105	UR907QSQ	Samples
DS90UR907QSQX/NOPB	ACTIVE	WQFN	NJK	36	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 105	UR907QSQ	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, Tl Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Apr-2013

TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

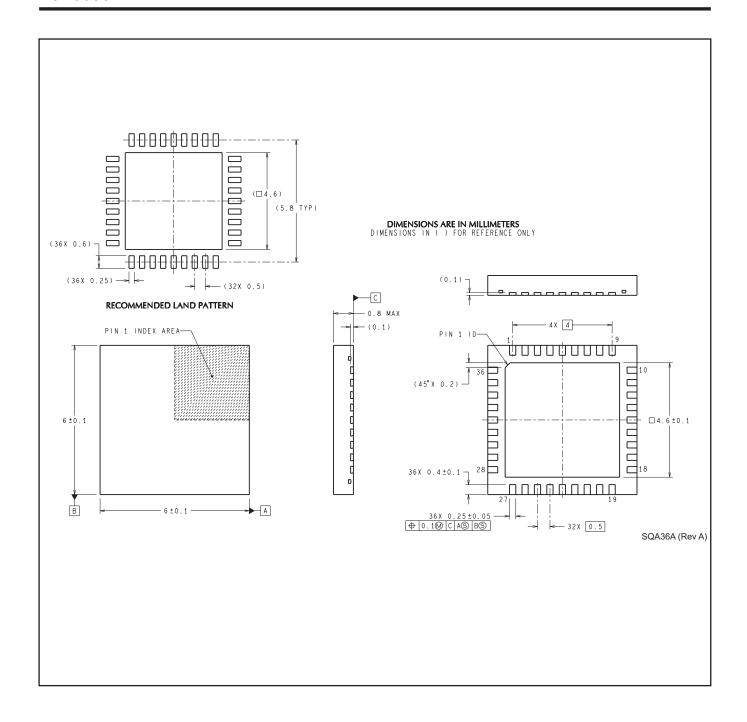
Device Device	Package Drawing		SPQ	Reel Diameter	Reel Width	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant	
	Type	Drawing				W1 (mm)	()	()	()	()	()	Quadrant
DS90UR907QSQ/NOPB	WQFN	NJK	36	1000	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1
DS90UR907QSQE/NOPB	WQFN	NJK	36	250	178.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1
DS90UR907QSQX/NOPB	WQFN	NJK	36	2500	330.0	16.4	6.3	6.3	1.5	12.0	16.0	Q1

www.ti.com 24-Apr-2013



*All dimensions are nominal

7 til dillionolorio aro nominal								
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
DS90UR907QSQ/NOPB	WQFN	NJK	36	1000	367.0	367.0	38.0	
DS90UR907QSQE/NOPB	WQFN	NJK	36	250	213.0	191.0	55.0	
DS90UR907QSQX/NOPB	WQFN	NJK	36	2500	367.0	367.0	38.0	



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID www.ti-rfid.com

OMAP Applications Processors <u>www.ti.com/omap</u> TI E2E Community <u>e2e.ti.com</u>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>